LNCT22PK01WW

Panasonic

Description

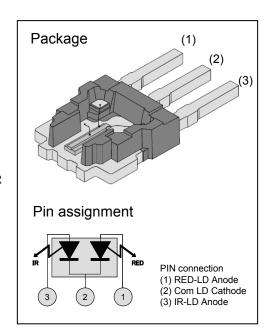
LNCT22PK01WW is a MOCVD fabricated 660 nm and 780 nm band dual wavelength laser diode with multi quantum well structure, adapting open type frame package to reduce the size and weight.

Feature

- Dual wavelength: 661 nm (typ) and 785 nm (typ)
- High output power: 280 mW (pulse) for Red and 380 mW (pulse) for IR
- Package : Flat package
- Operating temperature : Max. +85°C

Application

- · Optical disk drive
- Sensing
- Industrial use



Absolute Maximum Ratings 3)

LD	Item	Symbol	Value	Unit	Condition
RED	Output nower	Po	100	mW	CW
	Output power	FU	280	mW	pulse 1)
	Reverse voltage	Vr	1.5	V	CW
	Operating case temperature	Tc	-10 to +85	°C	CW/pulse
IR	Output nower	Ро	200	mW	CW
	Output power		380	mW	pulse 2)
	Reverse voltage	Vr	1.5	V	CW
	Operating case temperature	Tc	-10 to +85	°C	CW/pulse
	Storage temperature	Tstg	-40 to +85	°C	

Note) 1) Pulse width ≤ 30 ns, duty $\leq 33\%$ for RED-LD

- 2) Pulse width \leq 100 ns, duty \leq 50% for IR-LD
- 3) These ratings are guaranteed only when RED-LD or IR-LD is turned on individually.

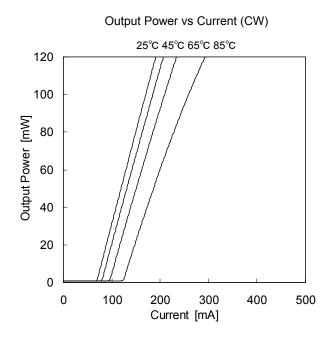
Electrical and Optical Characteristics

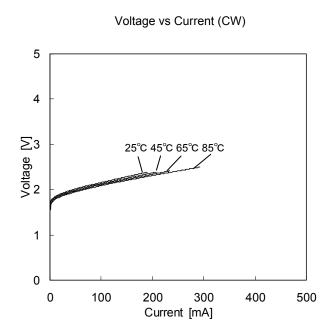
Tc =25°C, CW, Po=100mW for RED-LD, 200mW for IR-LD

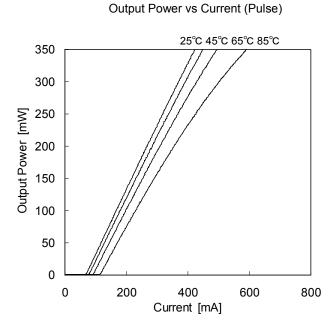
LD	Item		Symbol	Min.	Тур.	Max.	Unit	Condition
RED	Threshold current		Ith	-	65	95	mA	
	Operating current		lop	-	160	230	mA	
	Operating voltage		Vop	-	2.3	3.0	V	
	Wavelength		λ	656	661	665	nm	
	Beam divergence	Parallel	θh	7.5	9.0	13.0	deg	FWHM
		Perpendicular	θν	13.0	16.0	19.5	deg	FWHM
IR	Threshold current		Ith	-	60	95	mA	
	Operating current		lop	-	260	380	mA	
	Operating voltage		Vop	-	2.4	3.2	V	
	Wavelength		λ	777	785	791	nm	
	Beam divergence	Parallel	θh	6.0	7.5	11.5	deg	FWHM
		Perpendicular	θν	12.0	15.0	19.0	deg	FWHM

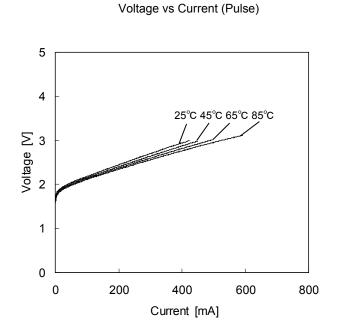
FWHM : Full width at half maximum

Representative Characteristics [RED-LD]



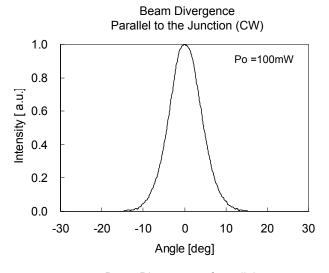


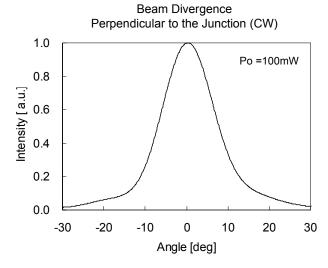


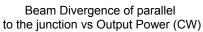


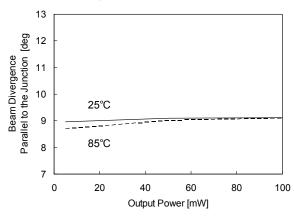
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Representative Characteristics [RED-LD]

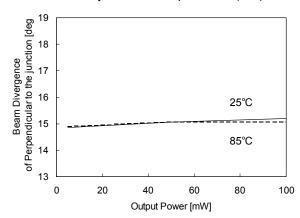




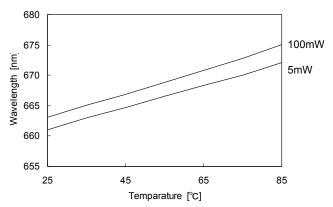




Beam Divergence of Perpendicular to the junction vs Output Power (CW)

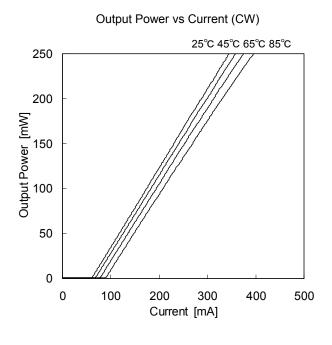


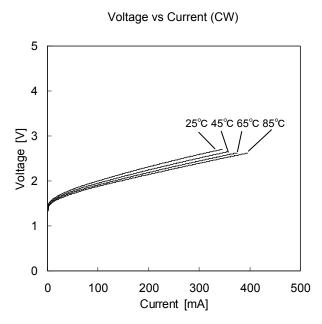
Wavelength vs Temperature (CW)

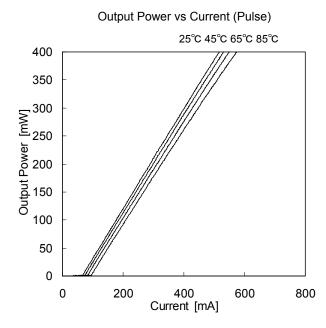


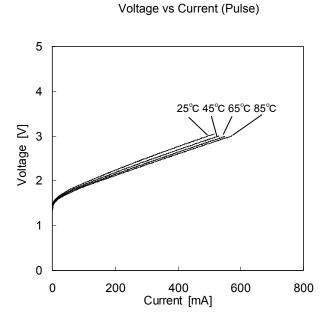
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Representative Characteristics [IR-LD]



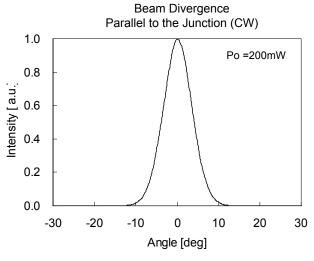




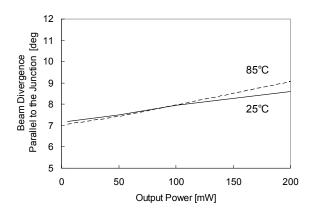


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Representative Characteristics [IR-LD]



Beam Divergence of parallel to the junction vs Output Power (CW)



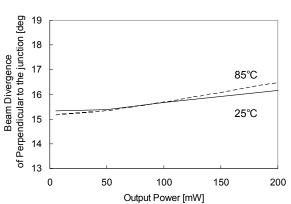
1.0
0.8
0.8
0.6
0.2
0.0
-30 -20 -10 0 10 20 30

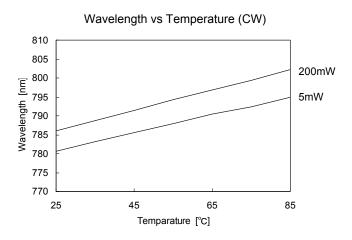
Beam Divergence

Perpendicular to the Junction (CW)

Beam Divergence of Perpendicular to the junction vs Output Power (CW)

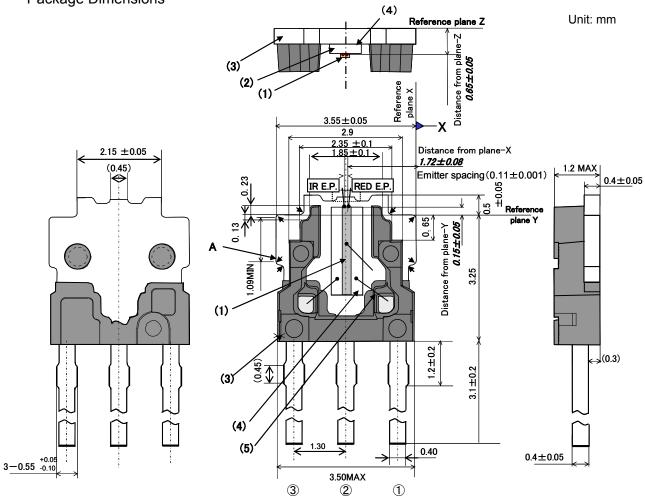
Angle [deg]





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Package Dimensions



- (1) LD Chip (2) Submount
- (3) Package
- (4) Ag Paste (5) Au Wire
- E.P. = Emitting point
- General corner R is 0.25mm

LNCT22PK01WW

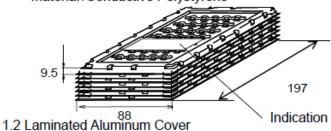
Panasonic

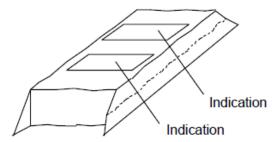
Packing Specification

1 Packing Material

1.1 Tray

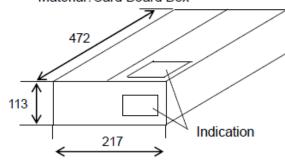
Material: Conductive Polystyrene





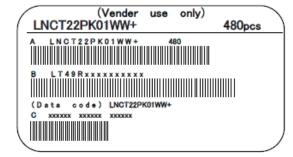
1.3 Packing Case

Material: Card Board Box

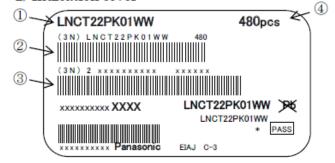


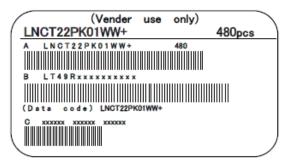
※As for label indication except ①(Order person part number),②(Order) person part number and Quantity), 3 (Serial number and Corporate code), 4 (Quantity), the information only for our process control, therefore please note that revision without notice might be done due to improvement etc.

1) Indication tray

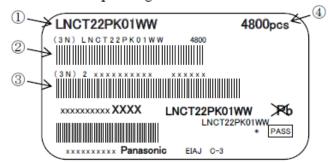


Indication cover





3) Indication packing case



2 Packaging Quantity

Form	Quantity	Contents	Note
Tray	n=80		
Laminated Aluminum Cover	n=480	Tray 7	Wrap The Product and The Desiccant
Packing Case	n=4800	Al Cover 10	

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Cautions

■ Laser class

This product is ranked in class IIIb laser according to IEC60825-1 and JIS standard 6802 "Laser Product Emission Safety Standards", so that safety protection is necessary when laser beam is radiated.

■ Flat package laser diode (FLD)

This product is adopting open type plastic package for the reduction of size and weight, so please take care of dust and touching laser diode with tweezers.

■ Prevention of Electrostatic discharge (ESD) and surge stress

Semiconductor laser diode is sensitive device to ESD and surge, so that sufficient cautions are needed. If electric pulses that may cause emission are inputted, the laser itself will be damaged by light intensity and will bring the laser diode degradation in a short time. Therefore, taking all possible measures against ESD and surge for FLD usage is strongly requested.

■ Heat sink design

If case temperature becomes higher, the life of semiconductor laser diode becomes shorter. So it is important that design for heat radiation is appropriated. Especially it is effective to make the heat radiation from metal moiety of the package back side, locating under the submount and laser diode.

■ Precaution at soldering

When soldering, please give attention to the mechanical stress and the temperature because of using Ag paste. Temperature of die-pad portion should be less than 200°C. It is recommended to radiate heat by putting heat sink on the package.

Soldering temperature and time

Temperature : Less than 360°C (FLD only)

Less than 380°C (FLD with holder for heat radiation)

Time : Within 5sec (Recommend within 3sec)

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